

Product Summary

Symbol	Value	Unit
$I_{T(RMS)}$	4.0	A
$V_{DRM} V_{RRM}$	600 / 800	V
V_{TM}	1.55	V

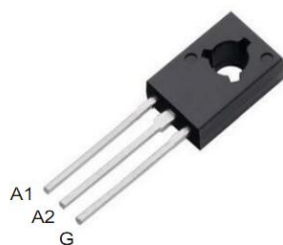
Feature

With high ability to withstand the shock loading of large current, With high commutation performances, 4 quadrants products especially recommended for use on inductive load.

Application

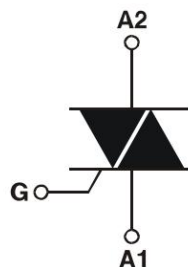
Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

Package

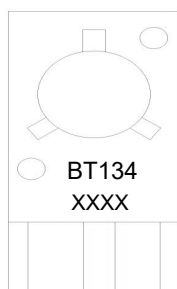


TO-126

Circuit diagram



Marking



Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	600 / 800	V
Repetitive peak reverse voltage	V_{RRM}	600 / 800	V
RMS on-state current	$I_{T(RMS)}$	4	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I_{TSM}	25	A
I^2t value for fusing (tp=10ms)	I^2t	3.1	A ² s
Critical rate of rise of on-state current ($I_G = 2 \times I_{GT}$)	di_T/dt	I - II - III	50
		IV	10
Peak gate current	I_{GM}	2	A
Average gate power dissipation	$P_{G(AV)}$	0.5	W
Junction Temperature	T_J	-40 ~ +125	°C
Storage Temperature	T_{STG}	-40 ~ +150	°C

Electrical characteristics (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition		Value		Unit
Gate trigger current	I _{GT}	V _D =12V I _T = 0.1A T _j =25°C	I - II -III	MAX.	10	mA
			IV		25	
Gate trigger voltage	V _{GT}		I - II -III-IV	MAX.	1.3	V
Gate non-trigger voltage	V _{GD}	V _D =V _{DRM} T _j =125°C		MIN.	0.2	V
latching current	I _L	V _D =12V I _{GT} = 0.1A T _j =25°C	I -III-IV	MAX.	15	mA
			II		20	
Holding current	I _H		I - II -III-IV	MAX.	15	mA
Critical-rate of rise of commutation voltage	dV _D /dt	V _D =2/3V _{DRM} Gate Open T _j =125°C		MIN.	20	V/μs
STATIC CHARACTERISTICS						
Forward "on" voltage	V _{TM}	I _{TM} =6A tp=380μs		MAX.	1.55	V
Repetitive Peak Off-State Current	I _{DRM}	V _D =V _{DRM} V _R =V _{RRM}	T _j =25°C	MAX.	5	μA
Repetitive Peak Reverse Current	I _{RRM}		T _j =125°C	MAX.	500	μA
THERMAL RESISTANCES						
Thermal resistance	Rth(j-c)	Junction to case(AC)		TYP.	3	°C/W
	Rth(j-a)	Junction to ambient		TYP.	100	°C/W

Typical Characteristics

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

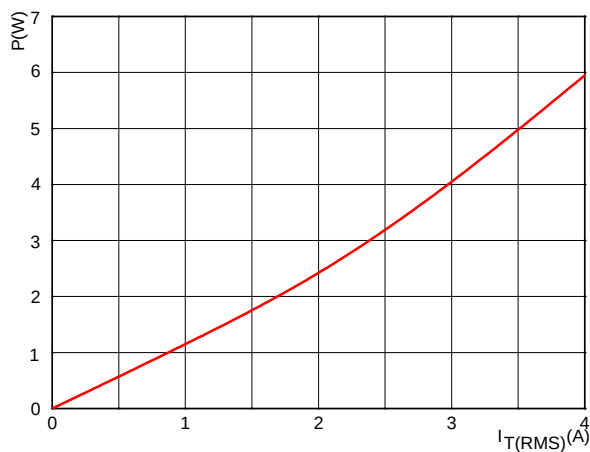


FIG.2: RMS on-state current versus case temperature (full cycle)

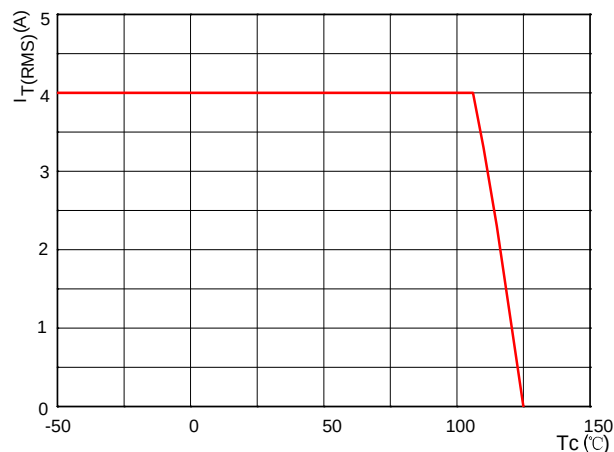


FIG.3: Surge peak on-state current versus number of cycles

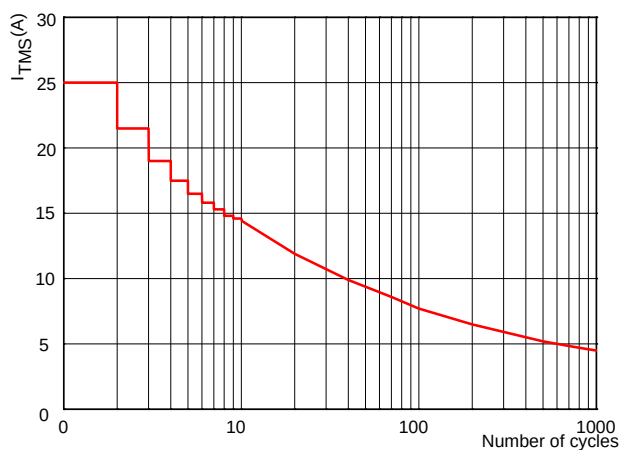


FIG.4: On-state characteristics (maximum values)

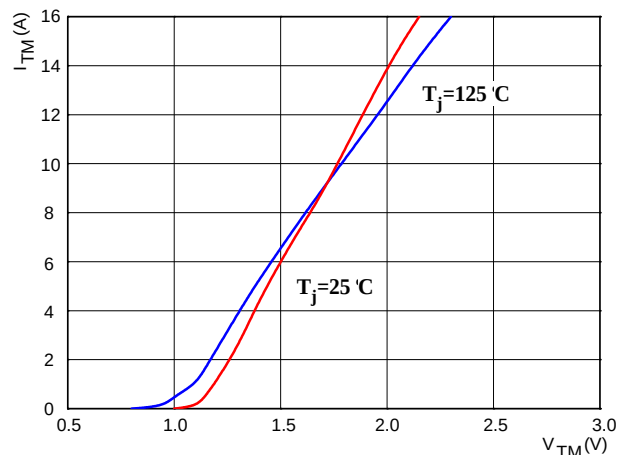


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10ms$

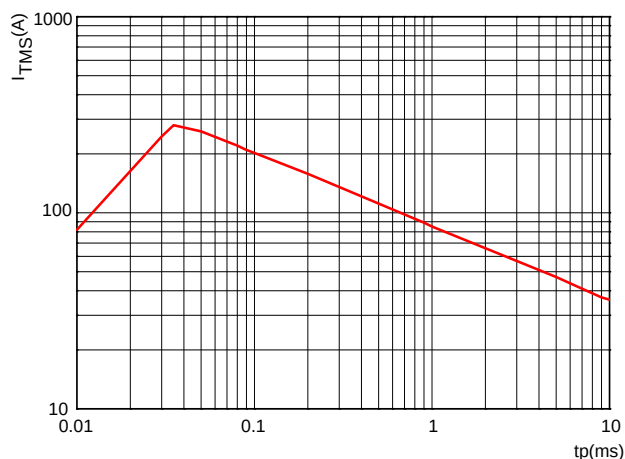
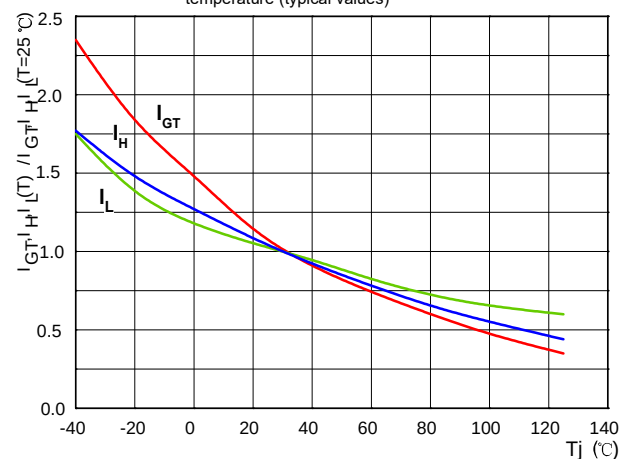
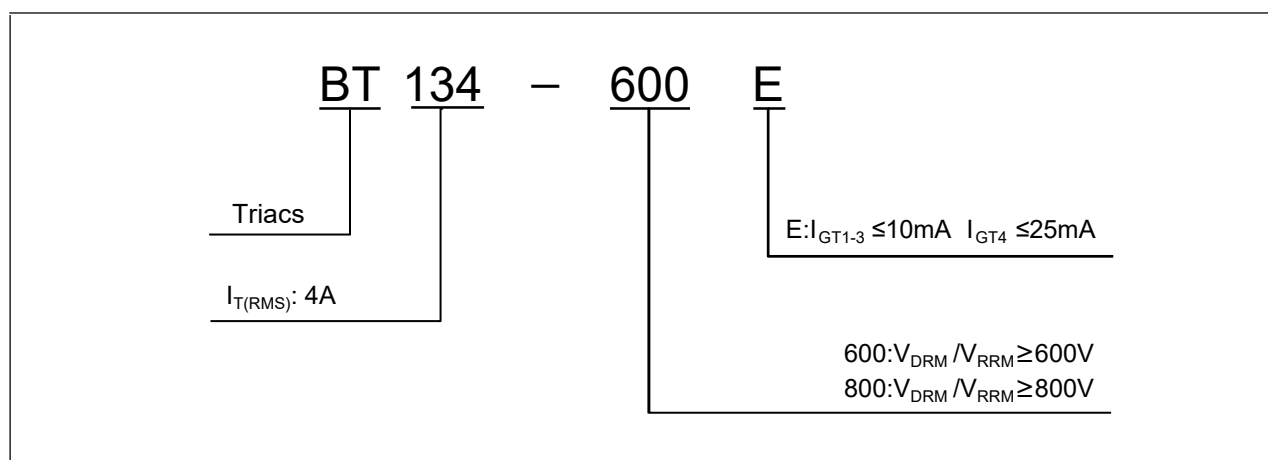


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



Ordering Information



TO-126 Package Information

